IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Jack O. Chu, et al.

Examiner:

Unassigned

Serial No:

To be assigned

Art Unit:

Unassigned

Filed:

Herewith

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Docket: YOR920010308US2 (16315A)

For: EPITAXIAL AND POLYCRYSTALLINE

GROWTH OF Si_{1-x-y} Ge_xC_y AND Si_{1-y}C_y
ALLOY LAYERS ON Si BY UHV-CVD

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Dated: February 10, 2004

Commissioner for Patents United States Patent Office Alexandria, VA 23313-1450

PRELIMINARY AMENDMENT

Sir:

In connection with filing the above-identified application under 37 C.F.R.

§1.53(b), applicants submit the following amendments and remarks for consideration by the

Examiner and entry of record in the above-identified patent application.

CERTIFICATE OF MAILING BY "EXPRESS MAIL"

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I hereby certify that this correspondence is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37) C.F.R. § 1.10 on the date indicated above and is addressed to the Commissioner for Patents and Trademarks, Alexandria, VA 22313-1450 on February 10, 2004.

Dated: February 10, 2004

Leske Szszivos, Ph.D.